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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/662,609	09/15/2003	Chih-Yang Pai	TSM03-0146	2342
25962	7590 12/09/2004		EXAM	INER
SLATER & MATSIL, L.L.P. 17950 PRESTON RD, SUITE 1000 DALLAS, TX 75252-5793			LE, THAO X	
			ART UNIT	PAPER NUMBER
2112213, 111			2814	

DATE MAILED: 12/09/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/662,609	PAI ET AL.			
Office Action Summary	Examiner	Art Unit			
	Thao X Le	2814			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply within the statutory minimum of thirty (30 vill apply and will expire SIX (6) MONTHS, cause the application to become ABANI	be timely filed O) days will be considered timely. From the mailing date of this communication. DONED (35 U.S.C. § 133).			
Status					
1)⊠ Responsive to communication(s) filed on 23 N	ovember 2004.				
•	action is non-final.				
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under E	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims					
4) Claim(s) 1-33 is/are pending in the application.					
4a) Of the above claim(s) <u>1-23</u> is/are withdrawn from consideration.					
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>24-33</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	r election requirement.				
Application Papers					
9) The specification is objected to by the Examiner.					
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).					
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached O	ffice Action or form PTO-152.			
Priority under 35 U.S.C. § 119					
 12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 		19(a)-(d) or (f).			
2. Certified copies of the priority document		lication No			
3. Copies of the certified copies of the prior					
application from the International Bureau					
* See the attached detailed Office action for a list		ceived.			
Attachment(s)	-				
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)		mary (PTO-413) lail Date			
Notice of Draftsperson's Patent Drawing Review (PTO-946) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date		mal Patent Application (PTO-152)			

DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of claims 24-33 in the reply filed on 23 Nov. 2004 is acknowledged.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 24-33 are rejected under 35 U.S.C. 102(b) as being anticipated by US 5674770 to Lee et al.

Regarding claim 24, Lee discloses a method of forming a semiconductor device, the method comprising: forming a cell gate oxide 3 (left portion), fig. 1, column 3 line 6, in a cell region; forming a logic gate oxide 3 (right portion), fig. 1, in a periphery region, forming a first doped polysilicon layer 4, column 3 lines 10 and 14, fig. 1, on the cell gate oxide 3; and forming a second polysilicon layer 7, column 3 line 39, fig. 3, on the logic gate oxide 3 and the first doped polysilicon layer 4.

Regarding claims 25-26, 30, and 32-33 Lee discloses the method of claim 24 wherein the second polysilicon layer 7 positioned above the cell gate oxide 3 is a p-type doped polysilicon,

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the second polysilicon layer is doped with a material selected from the group consisting essentially of phosphorous, nitrogen, arsenic, and antimony, column 3 line 46

Regarding claims 27-28, Lee discloses the method of claim 24 wherein the step of forming a first polysilicon layer 4 is performed by depositing by furnace an in-situ doped polysilicon, column 3 line 15, wherein depositing by furnace is performed at a temperature of about 540°C to about 640°C, column 3 line 13.

Regarding claim 29, Lee discloses the method of claim 24 wherein the second polysilicon layer 7 is formed of undoped polysilicon, column 3 line 45.

Regarding claim 31, Lee discloses the method of claim 30 further comprising the step of doping the second polysilicon layer 7 located above the logic gate oxide with an n-type dopant, column 5 lines 5-10. Inherently, Lee discloses layer 7 can be doped with either N-type or P-type dopant.

Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thao X Le whose telephone number is (571) 272-1708. The examiner can normally be reached on M-F from 8:00 AM - 4:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thao X. Le 07 Dec. 2004

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